# NSN 5961-01-175-3349

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# **Inclosure Material:**

Metal

**Overall Length:** 

0.260 inches

# Terminal Length:

1.500 inches

# **Overall Diameter:**

0.370 inches

### Internal Configuration:

Junction contact

## Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-5

### **Mounting Method:**

Terminal

### Terminal Circle Diameter:

0.200 inches

### **Features Provided:**

Hermetically sealed case

## Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

300.0 breakdown voltage, collector-to-base, emitter open and 250.0 breakdown voltage, collector-to-emitter, base open and 7.0

breakdown voltage, emitter-to-base, collector open

## **Current Rating Per Characteristic:**

1.00 amperes source cutoff current and 0.50 amperes source cutoff current

## **Power Rating Per Characteristic:**

10.0 watts small-signal input power, common-collector preset

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

## **Special Features:**

Junction pattern arrangement: npn

## **Terminal Type And Quantity:**

3 uninsulated wire lead

#### Shelf Life:

N/a

## Unit Of Measure:

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## Demilitarization:

No

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